

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	7	ocl and "372"/\$.ccls.	USPAT	OR	OFF	2008/01/02 09:21
L2	0	butt near3 coupl\$3 near3 fib\$3 same mqw with width and semiconductor near3 laser	USPAT	OR	OFF	2008/01/02 09:22
L3	0	butt\$3 near3 fib\$3 same mqw with width and semiconductor near3 laser	USPAT	OR	OFF	2008/01/02 09:23
L4	0	butt\$3 near3 fib\$3 same mqw and semiconductor near3 laser	USPAT	OR	OFF	2008/01/02 09:23
L5	13	butt\$3 near3 fib\$3 and mqw same semiconductor near3 laser	USPAT	OR	OFF	2008/01/02 09:25
L6	44	but\$3 with fib\$3 and mqw same semiconductor near3 laser	USPAT	OR	OFF	2008/01/02 09:27
L7	49	pigtail with semiconductor near3 laser	USPAT	OR	OFF	2008/01/02 09:28
L8	3	pigtail with semiconductor near3 laser and mqw	USPAT	OR	OFF	2008/01/02 09:28
S1	4	(("6333945") or ("20020041613") or ("20040089866") or ("6606334")).PN.	US-PGPUB; USPAT	OR	OFF	2007/12/31 07:21
S2	1	substrate near3 inp and single near3 mode near3 fib\$3 and mqw and fundamental near3 lateral near3 mode	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT	OR	ON	2007/12/31 08:30
S3	28	substrate near3 inp and single near3 mode near3 fib\$3 and mqw and fundamental near3 mode	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT	OR	ON	2007/12/31 07:23
S4	52	substrate and inp and single near3 mode near3 fib\$3 and mqw and fundamental near3 mode\$1	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT	OR	ON	2007/12/31 08:31
S5	24	S4 not S3	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT	OR	ON	2007/12/31 09:35

EAST Search History

S6	160	semiconductor near3 laser and coupl\$3 with single near3 mode near3 fib\$3 and mqw	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT	OR	ON	2007/12/31 09:42
S7	81	S6 and "372"\$/ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT	OR	ON	2007/12/31 09:37
S8	6	semiconductor near3 laser and coupl\$3 with single near3 mode near3 fib\$3 and mqw with width	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT	OR	ON	2007/12/31 10:36
S9	9	semiconductor near3 laser and substrate near3 inp and clad\$4 near3 inp and mqw with width and fundamental near3 mode\$1	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT	OR	ON	2007/12/31 10:44
S10	9	semiconductor near3 laser and substrate near3 inp and clad\$4 near3 inp and mqw and fundamental near3 mode\$1 and sch	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT	OR	ON	2007/12/31 10:52
S11	202	semiconductor near3 laser and substrate near3 inp and clad\$4 near3 inp and mqw and sch and ingaasp	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT	OR	ON	2007/12/31 10:52
S12	202	semiconductor near3 laser and substrate near3 inp and clad\$4 near3 inp and mqw and sch and ingaasp and sch	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT	OR	ON	2007/12/31 11:04
S13	68	semiconductor near3 laser and substrate near3 inp and clad\$4 near3 inp and mqw and sch and clad\$4 near3 ingaasp and sch	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT	OR	ON	2007/12/31 11:05

EAST Search History

S14	68	semiconductor near3 laser and substrate near3 inp and clad\$4 near3 inp and mqw and sch and clad\$4 near3 ingaasp	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT	OR	ON	2007/12/31 11:05
-----	----	-------------------------------------------------------------------------------------------------------------------	-------------------------------------------------	----	----	------------------